

V. Maulerova–Subert, I. Dawson, E. Garutti, M.Moll



NIEL(non-ionizing energy loss)

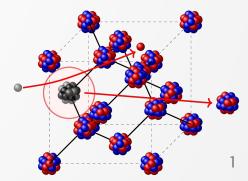
Simulations and displacement damage studies towards a more complex NIEL concept for radiation damage modelling and prediction,





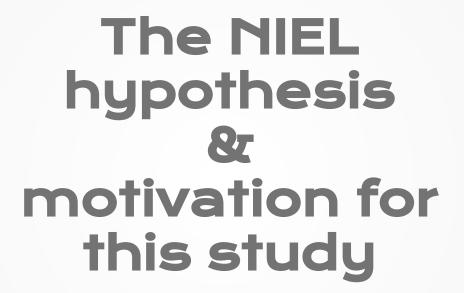
Previous RD50 contributions:

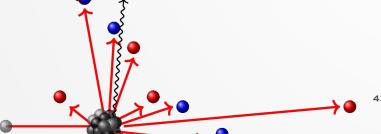
https://indico.cern.ch/event/1074989/contributions/4601973/ (Valencia) https://indico.cern.ch/event/1157463/contributions/4922734/ (CERN) https://indico.cern.ch/event/1132520/contributions/5147237/ (Seville)



CONTENTS

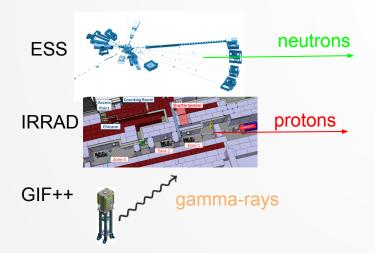
- 1. The **NIEL** hypothesis & motivation for this study
- **2. Overview** of the Integration of simulations
- 3. Geant4: simulations of Primary knocked-on atoms (PKA) <- 3GeV-24 GeV newly simulated (corrected physics list)
- **4. TRIM:** Secondary recoils and atomic cascades
- **5. OPTICS:** (Ordering points to identify clustering structure): Isolated vs clustered defects (new Integration of TRIM and OPTICS)
- **6. Atomic displacements** produced by high energy particles
 - a. NIEL curve updated (New integration of G4 and TRIM)
 - b. Clustered vs. isolated defects (New integration of G4, TRIM and OPTICS)
- **7. Summary** and next steps





NIEL (non-ionizing energy loss)

- NIEL is a physical quantity describing the non-ionizing energy loss as the particle travels through the medium.
- The amount of NIEL can be correlated to the ammount of radiation damage (NIEL scaling model) and therefore to predict the life time of the detectors
- NIEL scaling assumption is used by the LHC experiments and beyond (fluence is expressed in ~1 MeV neutron eq. ~ 95 MeV mb)



 Long term goal: revisit the damage factors stated by different irradiation facilities and used by the experiments.

NIEL (non-ionizing energy loss)

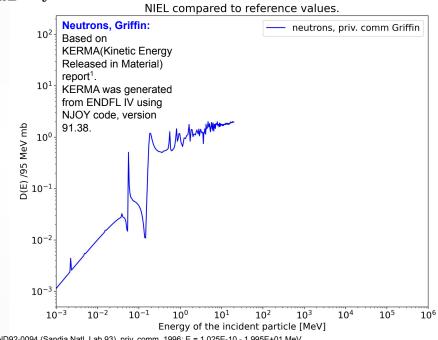
$$NIEL(T_0) = rac{N_A}{A} \sum_i \int_{T_{min}}^{T_{max}} Q(T) Tig(rac{d\sigma}{dT}ig)_i dT$$

For Silicon in RD-48 collaboration, A. Vasilescu and G. Lindstrom collected data for neutrons, protons, electrons and pions.

- T₀: energy of incident particle
- T: energy transferred to the recoil atom
- (d_σ/dT): differential partial cross section for a particle with energy T₀ to create a recoil atom with energy T in the i-th reaction
- Q(T): partition factor giving the fraction of T that is going into further displacements
- **N**_A: Avogadro number
- A: atomic mass of target atom

Displacement damage function

$$NIEL(T_0) = rac{N_A}{A} D(T)$$



P.J. Griffin et al., SAND92-0094 (Sandia Natl. Lab.93), priv. comm. 1996: E = 1.025E-10 - 1.995E+01 MeV, (https://raw.githubusercontent.com/njoy/NJOY2016-manual/master/njoy16.pdf (page 120-130 for KERMA and damage))

NIEL (non-ionizing energy loss)

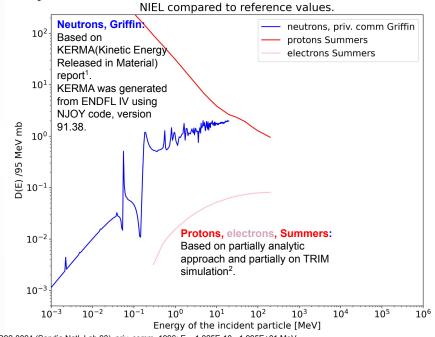
$$NIEL(T_0) = rac{N_A}{A} \sum_i \int_{T_{min}}^{T_{max}} Q(T) Tig(rac{d\sigma}{dT}ig)_i dT$$

For Silicon in RD-48 collaboration, A. Vasilescu and G. Lindstrom collected data for neutrons, protons. electrons and pions.

- T₀: energy of incident particle
- T: energy transferred to the recoil atom
- (dσ/dT): differential partial cross section for a particle with energy T₀ to create a recoil atom with energy T in the i-th reaction
- Q(T): partition factor giving the fraction of T that is going into further displacements
- **N**_A: Avogadro number
- A: atomic mass of target atom

Displacement damage function

$$NIEL(T_0) = rac{N_A}{A} D(T)$$



P.J. Griffin et al., SAND92-0094 (Sandia Natl. Lab.93), priv. comm. 1996: E = 1.025E-10 - 1.995E+01 MeV,

(https://raw.githubusercontent.com/njoy/NJOY2016-manual/master/njoy16.pdf (page 120-130 for KERMA and damage))

Summers, G. P., E. A. Burke, P. Shapiro, et al. "Damage Correlations in Semiconductors Exposed to Gamma, Electron and Proton Radiations." IEEE Transactions on Nuclear Science, vol. 40, no. 6, Dec. 1993, pp. 1372–79. IEEE Xplore, https://doi.org/10.1109/23.273529.

42st RD50 Workshop, 20.06.2023 Vendula Maulerova-Subert

NIEL (non-ionizing energy

 $NIEL(T_0) = rac{N_A}{A} \sum_i \int_{T_{min}}^{T_{max}} Q(T) T \left(rac{d\sigma}{dT}
ight)_i dT$

For Silicon in RD-48 collaboration, A. Vasilescu and G. Lindstrom collected data for neutrons,

- T_n: energy of incident particle
- T: energy transferred to the recoil atom
- (dσ/dT): differential partial cross section for a particle with energy $\mathbf{T}_{\mathbf{n}}$ to create a recoil atom with energy **T** in the i-th reaction
- Q(T): partition factor giving the fraction of T that is going into further displacements
- **N**_A: Avogadro number
- A: atomic mass of target atom

Displacement damage function

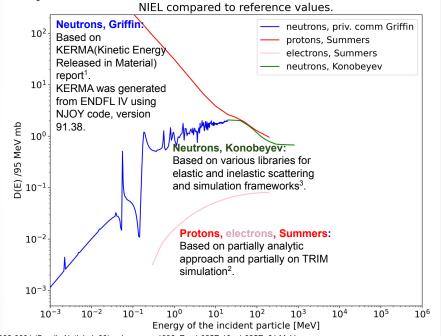
$$NIEL(T_0) = rac{N_A}{A} D(T)$$

MeV mb

P.J. Griffin et al., SAND92-0094 (Sandia Natl. Lab.93), priv. comm. 1996; E = 1.025E-10 - 1.995E+01 MeV. (https://raw.githubusercontent.com/njoy/NJOY2016-manual/master/njoy16.pdf (page 120-130 for KERMA and damage))

Summers, G. P., E. A. Burke, P. Shapiro, et al. "Damage Correlations in Semiconductors Exposed to Gamma, Electron and Proton Radiations." IEEE Transactions on Nuclear Science, vol. 40, no. 6, Dec. 1993, pp. 1372-79. IEEE Xplore, https://doi.org/10.1109/23.273529.

Konobeyev, Alexander Yu., et al. "Nuclear Data to Study Damage in Materials under Irradiation by Nucleons with Energies up to 25 GeV." Journal of Nuclear Science and Technology, vol. 39, no. sup2, Aug. 2002, pp. 1236-39. Taylor and Francis+NEJM, https://doi.org/10.1080/00223131.2002.10875327.



neutrons, priv. comm Griffin

protons (fit by M. Huhtinen)

protons measured data

neutrons (fit by M. Huhtinen)

High Energy

protons, neutrons: Derived from fitted

measurements of various authors4.

protons, Summers

electrons, Summers

NIEL (non-ionizing energy

 $NIEL(T_0) = rac{N_A}{A} \sum_i \int_{T_{min}}^{T_{max}} Q(T) T\left(rac{d\sigma}{dT}
ight)_i dT$

For Silicon in RD-48 collaboration, A. Vasilescu and G. Lindstrom collected data for neutrons,

NIEL compared to reference values.

leutrons, Konobeyev:

Based on various libraries for elastic and inelastic scattering

and simulation frameworks3.

Protons, electrons, Summers

approach and partially on TRIM

Based on partially analytic

simulation²

- T_n: energy of incident particle
- T: energy transferred to the recoil atom
- with energy **T** in the i-th reaction
- Q(T): partition factor giving the fraction of T that is going into further displacements
- **N**_A: Avogadro number
- A: atomic mass of target atom

Displacement damage function

$$NIEL(T_0) = rac{N_A}{A} D(T)$$

Neutrons, Griffin.

KERMA(Kinetic Energy

KERMA was generated

from ENDFL IV using

NJOY code, version

Released in Material)

Based on

report1.

91.38.

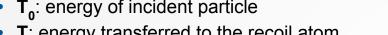
 0 D(E) /95 MeV mb $^{10^{0}}$ $^{10^{-1}}$

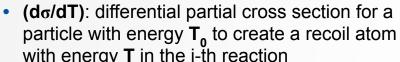
 10^{-2}

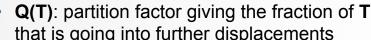
 10^{-3}

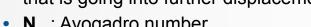
Konobeyev, Alexander Yu., et al. "Nuclear Data to Study Damage in Materials under Irradiation by Nucleons with Energies up to 25 GeV." Journal of Nuclear Science and Technology, vol. 39, no. sup2, Aug. 2002, pp. 1236-39. Taylor and Francis+NEJM, https://doi.org/10.1080/00223131.2002.10875327

 10^{-3} 10^{-2} 10^{-1} 100 10^{1} 10^{2} 10^{3} 10^{4} 105 10^{6} Energy of the incident particle [MeV] P.J. Griffin et al., SAND92-0094 (Sandia Natl. Lab.93), priv. comm. 1996; E = 1.025E-10 - 1.995E+01 MeV. (https://raw.githubusercontent.com/njoy/NJOY2016-manual/master/njoy16.pdf (page 120-130 for KERMA and damage)) Summers, G. P., E. A. Burke, P. Shapiro, et al. "Damage Correlations in Semiconductors Exposed to Gamma, Electron and Proton Radiations." IEEE Transactions on Nuclear Science, vol. 40, no. 6, Dec. 1993, pp. 1372-79. IEEE Xplore, https://doi.org/10.1109/23.273529.

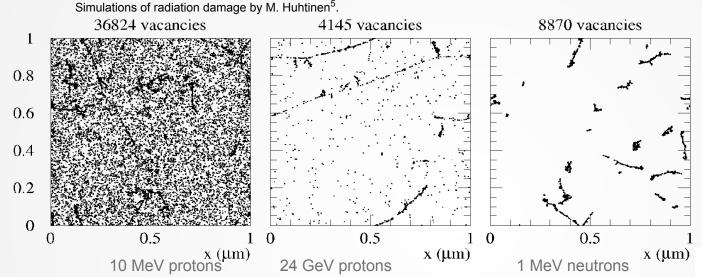






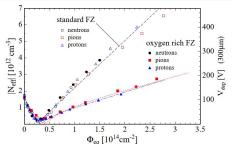


Revisiting NIEL

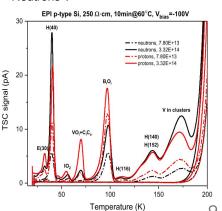


- NIEL doesn't distinguish between cluster and point displacement, i.e. the same displacament energy has a very different distribution of damage on the microscopic level.
- NIEL scaling violation reported in oxygen enriched silicon samples (CERN RD-48, Vdep (Φeq) dependence on particle type), differences between neutron's and proton's damage.

42st RD50 Workshop, 20.06.2023 Vendula Maulerova-Subert CERN RD48 : oxygen enriched silicon sensors⁶.



Radiation Damage in P-Type EPI Silicon Pad Diodes Irradiated with Protons and Neutrons⁷.



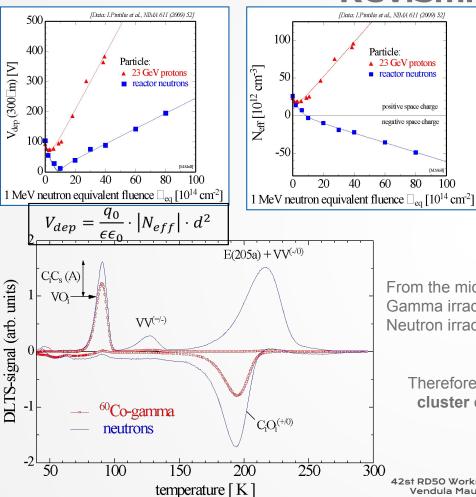
y (µm)

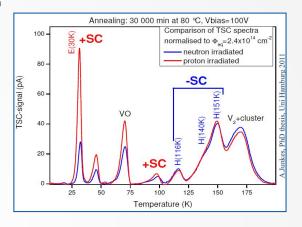
⁵⁾ Huhtinen, M. "Simulation of Non-Ionising Energy Loss and Defect Formation in Silicon." Nuclear Instruments and Methods in Physics Research Section A: Accelerators, Spectrometers, Detectors and Associated Equipment, vol. 491, no. 1, Sept. 2002, pp. 194–215. ScienceDirect, https://doi.org/10.1016/S0168-9002(02)01227-5.

⁶⁾ G. Lindström et al., Nucl. Instrum. Meth. A466 (2001) 308, doi:10.1016/S0168-9002(01)00560-5.

⁷⁾ Gurimskaya, Yana, et al. "Radiation Damage in P-Type EPI Silicon Pad Diodes Irradiated with Protons and Neutrons." Nuclear Instruments and Methods in Physics Research Section A: Accelerators, Spectrometers, Detectors and Associated Equipment, vol. 958, Apr. 2020, p. 162221. ScienceDirect,

Revisiting NIEL





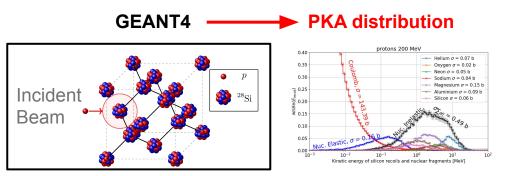
Protons: no space charge inversion Neutron: space inversion

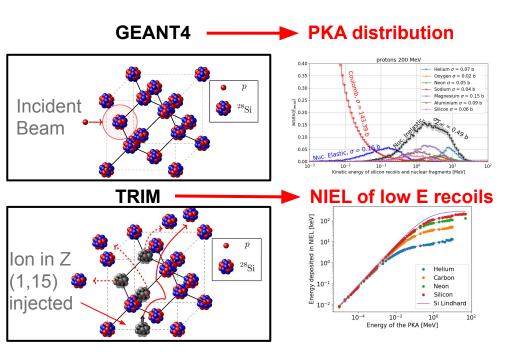
From the microscopic perspective: (DLTS measurement)

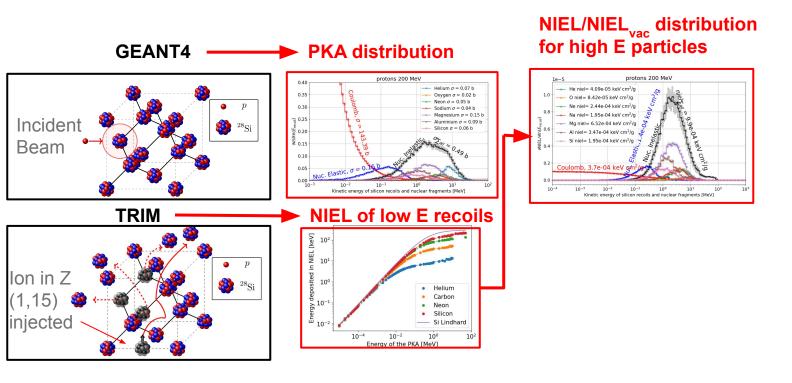
Gamma irradiation: only point defects

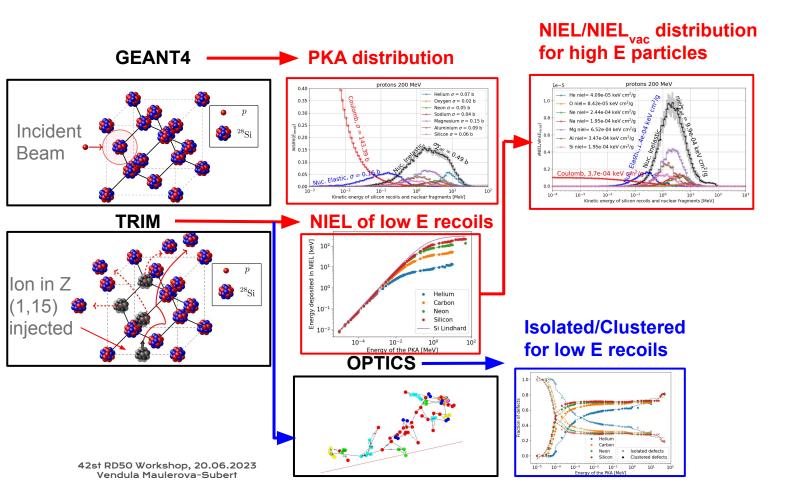
Neutron irradiation: cluster and point defects

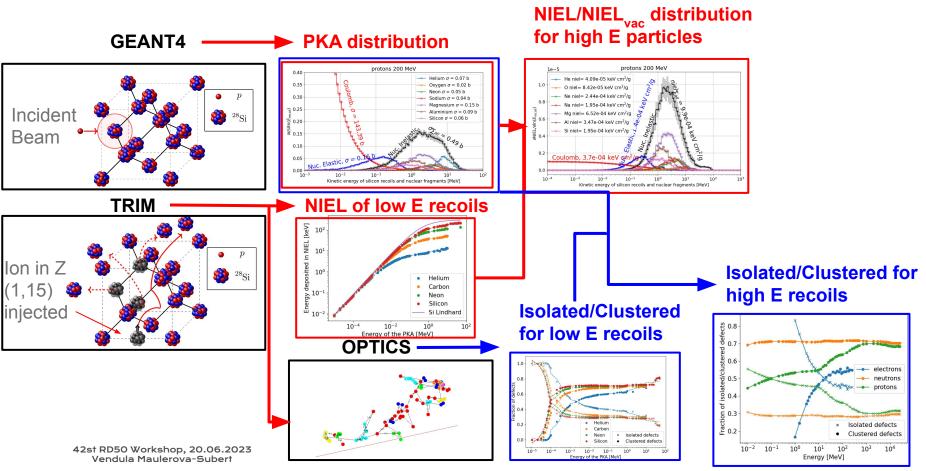
Therefore the aim of this study is to partition NIEL function into cluster contribution and point defects contribution.



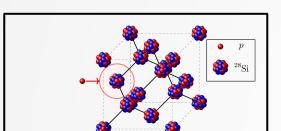


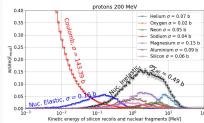






Geant4: Simulation of the PKA Primary knocked-on atoms (PKA) GEANT4 PKA distribution





Geant4 simulation framework

Geant4^{8,9}(for GEometry ANd Tracking) is a Monte Carlo simulation platform for the passage of particles through matter.

Define a geometry:



lmm x1 mm x100 µm

Choose a physics list:

- . For PKA (Primary knocked-on atoms):
 - a. *QGSP_BERT_HP* (Nuclear scattering < 3 GeV)
 - b. *QGSP_BERT_HP__SS* (Coulomb scattering for electrons)

Define a beam profile:



 Monochromatic pencil beam protons and neutrons of various energies (generally 10⁶-10⁸)

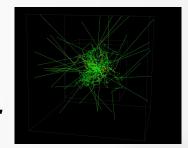
2. For electrons, also 1 um x 1 um beam investigated.

Launch a simulation:

QGSP_BERT_HP QGSP_BERT_HP__SS

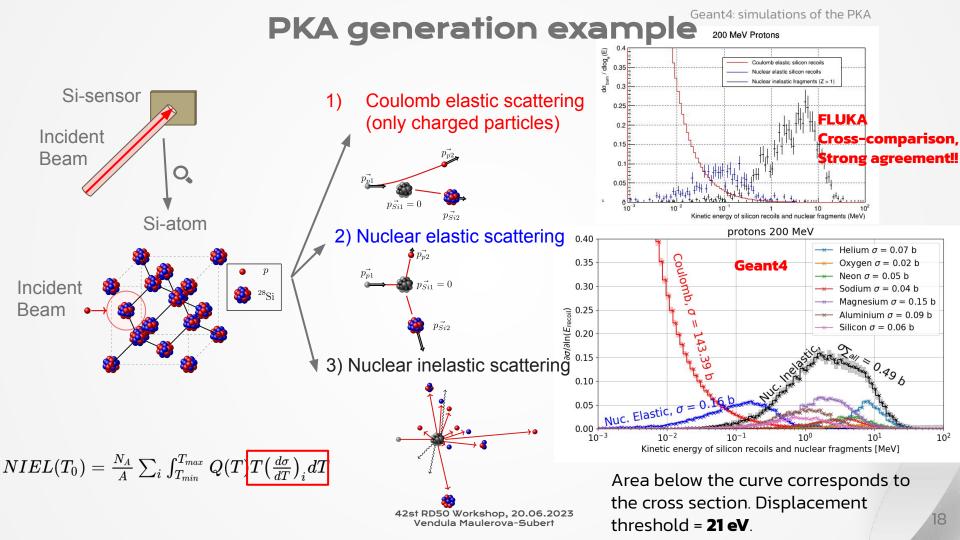


Analyze (c++, python), Save results.

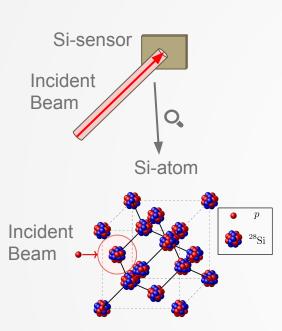


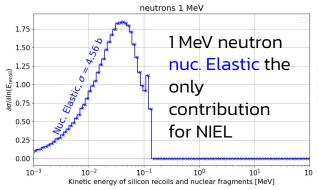
⁸⁾ Agostinelli, S., et al. "Geant4—a Simulation Toolkit." Nuclear Instruments and Methods in Physics Research Section A: Accelerators, Spectrometers, D Detectors and Associated Equipment, vol. 506, no. 3, July 2003, pp. 250–303. ScienceDirect, https://doi.org/10.1016/S0168-9002(03)01368-8.

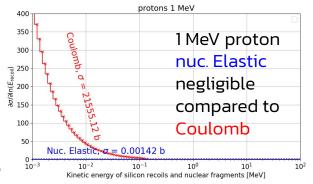
⁹⁾ Allison, J., K. Amako, J. Apostolakis, H. Araujo, et al. "Geant4 Developments and Applications." IEEE Transactions on Nuclear Science, vol. 53, no. 1, Feb. 2006, pp. 270–78. IEEE Xplore, https://doi.org/10.1109/TNS.2006.869826.

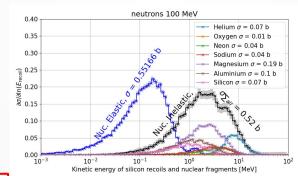


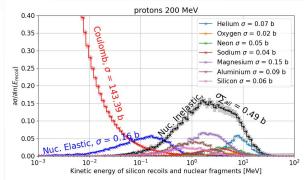
PKA generation examples



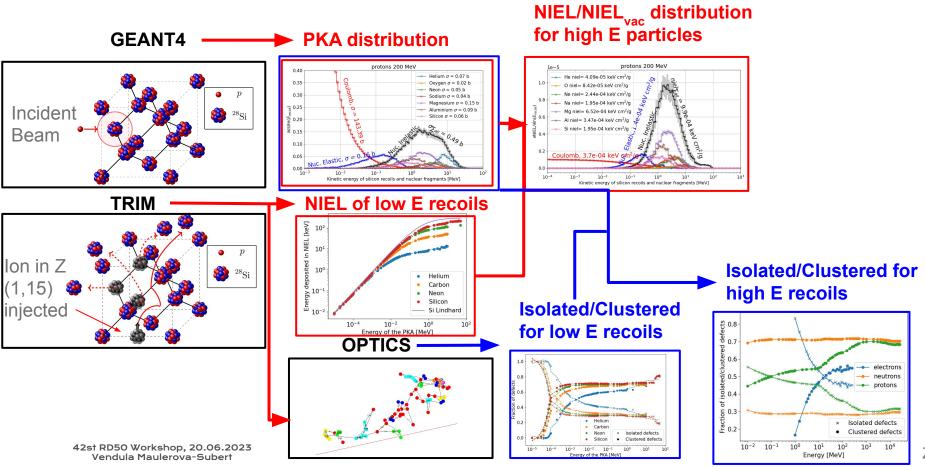




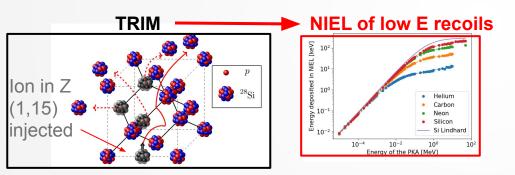




$$NIEL(T_0) = rac{N_A}{A} \sum_i \int_{T_{min}}^{T_{max}} Q(T) Tigg(rac{d\sigma}{dT}igg)_i dT$$



TRIM: Secondary recoils and atomic cascades



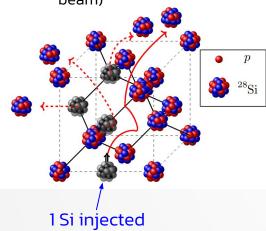
TRIM: 3D representation of 100 keV Si cascade

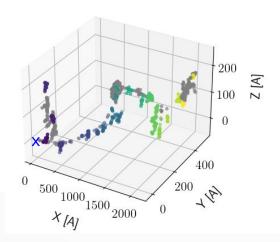
- TRIM simulations^{10,11}
- TRIM based on Binary Collison Approximation
- focus on the propagation of Si-recoil in Silicon (no incident beam)

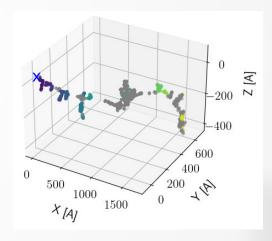
Example:

- 100 keV Silicon track
- originating from the blue cross (position 0,0,0)
- initial momentum in +x direction

Grey dots: isolated displacements Colored dots: clustered displacements



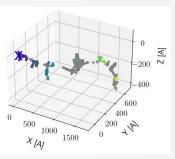




¹⁰⁾ SRIM, the Stopping and Range of lons in Matter, James F. Ziegler, J. P. Biersack, Matthias D. Ziegler 11) www.srim.org

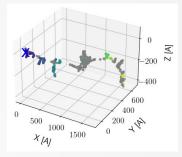
From TRIM it is possible to obtain:

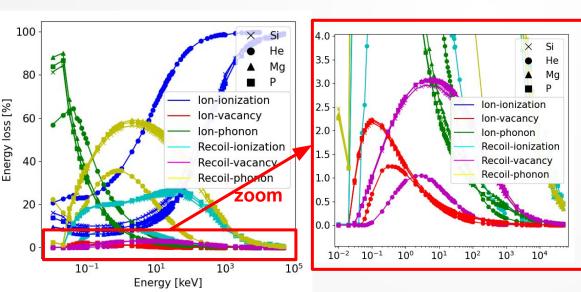
• Spatial distribution of the vacancies created by the low-energy recoils



From TRIM it is possible to obtain:

- Spatial distribution of the vacancies created by the low-energy recoils
- Fraction of the energy that is carried out by the:
 - Ionizing energy by the incident ion (Ion-ionization) or by the recoils (Recoil-ionization)
 - Phonon energy by the incident ion (Ion-phonon) or by the recoils (Recoil-phonon)
 - Energy transferred to kinetic and release energy of the vacancies (Ion-vacancy, Ion-phonon)

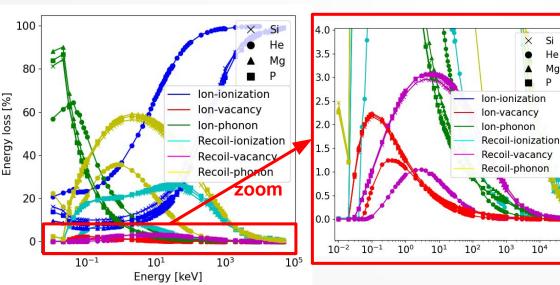


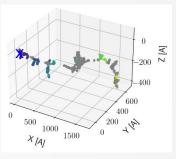


10⁴

From TRIM it is possible to obtain:

- Spatial distribution of the vacancies created by the low-energy recoils
- Fraction of the energy that is carried out by the:
 - Ionizing energy by the incident ion (Ion-ionization) or by the recoils (Recoil-ionization)
 - Phonon energy by the incident ion (Ion-phonon) or by the recoils (Recoil-phonon)
 - Energy transferred to kinetic and release energy of the vacancies (Ion-vacancy, Ion-phonon)
- NIEL =Ion +Ion +Recoil +Recoil +Recoil +Recoil +Recoil



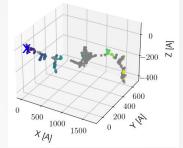


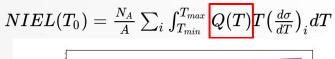
From TRIM it is possible to obtain:

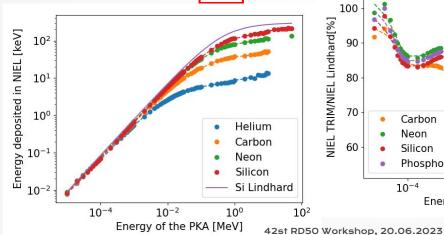
- Spatial distribution of the vacancies created by the low-energy recoils
- Fraction of the energy that is carried out by the:
 - Ionizing energy by the incident ion (Ion-ionization) or by the recoils (Recoil-ionization)
 - Phonon energy by the incident ion (Ion-phonon) or by the recoils (Recoil-phonon)
 - Energy transferred to kinetic and release energy of the vacancies (lon-vacancy, lon-phonon)

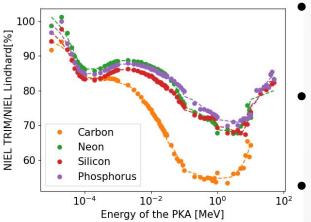
Vendula Maulerova-Subert

• NIEL =lon_{vacancy} +lon_{phonon} +Recoil_{vacancy} +Recoil_{phonon}





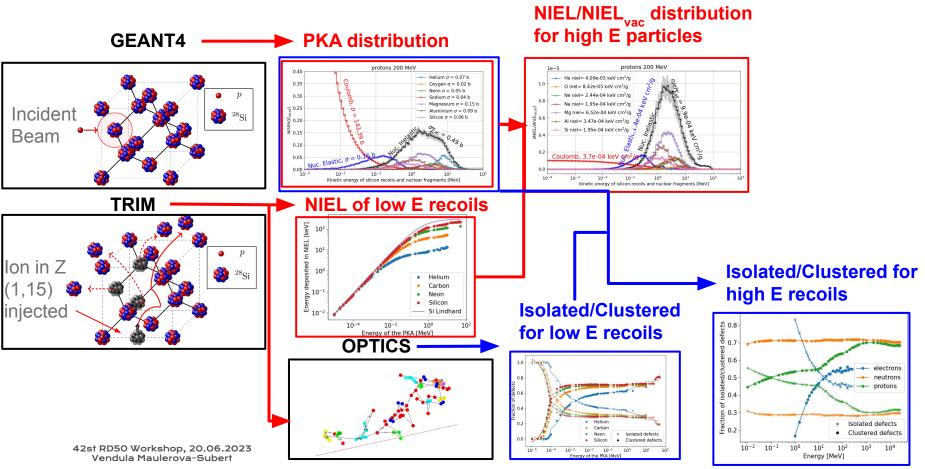




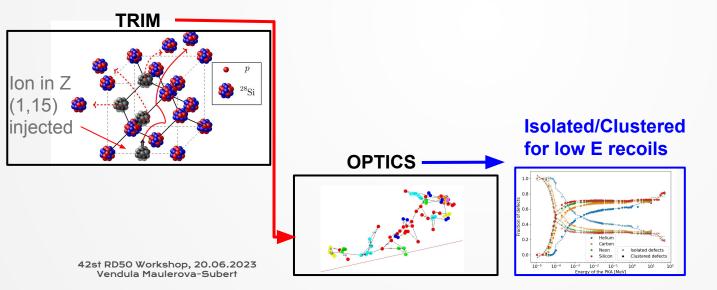
Alternative simplified solution used before: Lindhard¹² equations are overestimating the NIEL. Specifically this difference becomes very pronounced at high energies.

Lindhard should not be used for low Z ions.

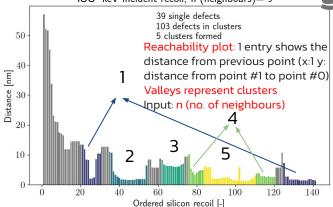
12) Principles of Radiation Interaction in Matter and Detection, Leroy, C., Rancoita, P.G., https://books.google.cz/books?id=w7-toAEACAAJ, 2016

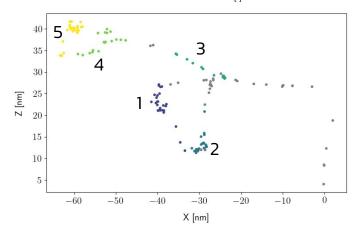


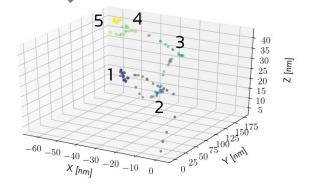
OPTICS^{15,16} (Ordering points to identify the clustering structure)



OPTICS¹³⁻¹⁵ (Ordering points to identify the clustering 100 keV incident recoil, n (neighbours)= 9 structure)







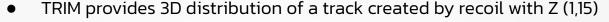
- Algorithm flow explain in the Appendix (Slide 34)
- Basic idea:
 - Ordering points and plotting their distances produces Reachability plot
 - Valleys in the reachability plot represent clusters
- Algorithm needs a user input: minimum number of samples to create cluster

13) Ankerst, Mihael, Markus M. Breunig, Hans-Peter Kriegel, and Jörg Sander. "OPTICS: ordering points to identify the clustering structure." ACM SIGMOD Record 28, no. 2 (1999): 49-60.

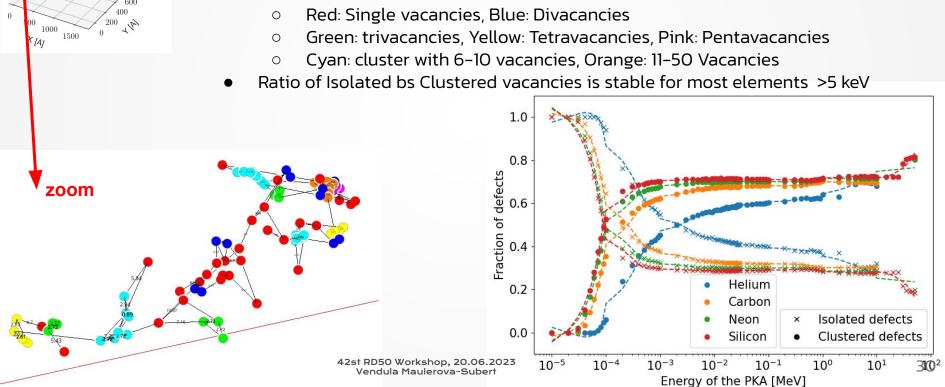
14) Schubert, Erich, Michael Gertz. "Improving the Cluster Structure Extracted from OPTICS Plots." Proc. of the Conference "Lernen, Wissen, Daten, Analysen" (LWDA) (2018): 318-329.

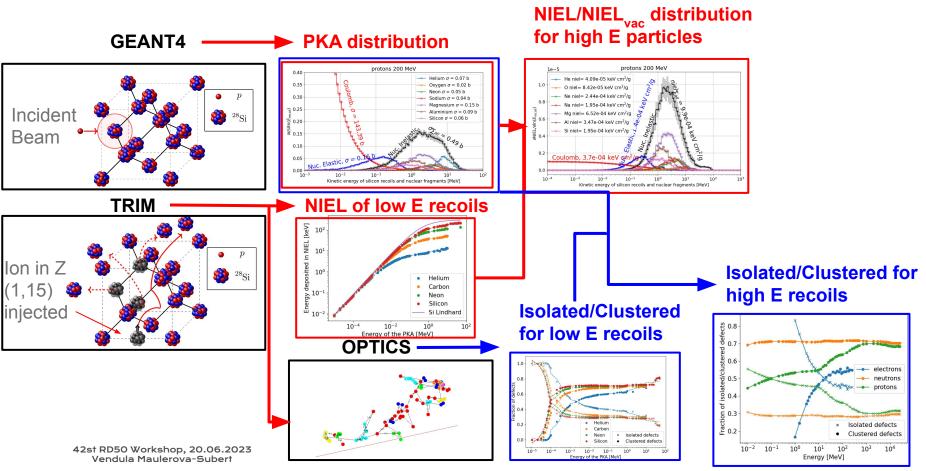
15) https://www.youtube.com/watch?v=CV0mWaHOTA8&t=133s tutorial

OPTICS: Isolated vs clustered defect

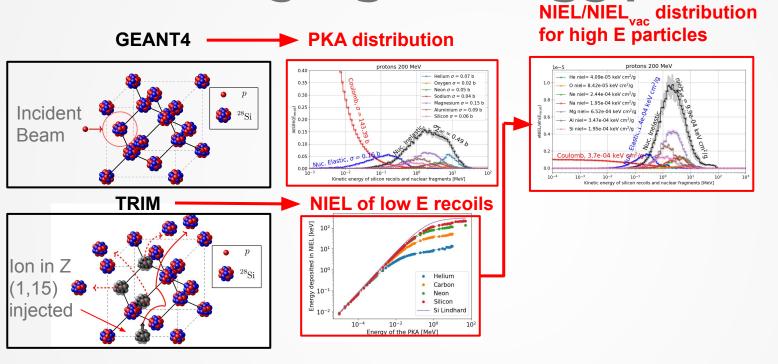


- OPTICS algorithm can further analyze this track
- Example cluster graph below (in order to be part of a cluster, the vacancies have to be closer then 4.7 A):



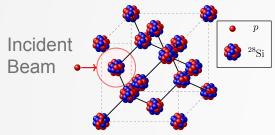


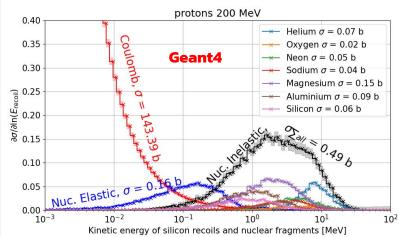
NIEL by high-energy particles



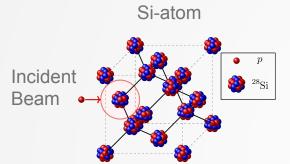
Integration of Geant4 PKA and TRIM NIEL

Si-atom

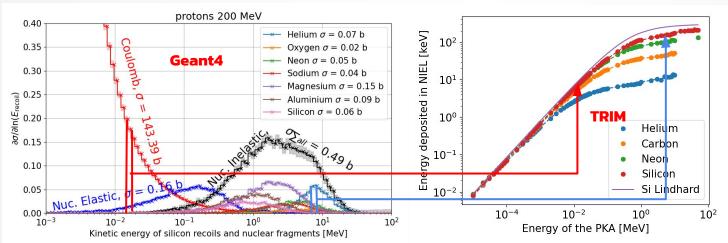




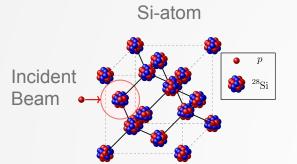
Integration of Geant4 PKA and TRIM NIEL



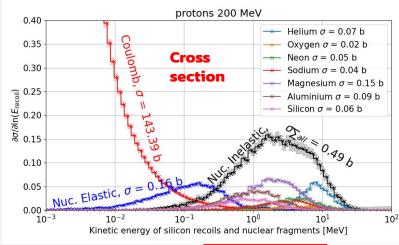
- 1) The PKA Energy distribution can be sliced.
- The slice of an Energy E for ion with proton number Z can be correlated to particular NIEL (NIEL_{vacancy})

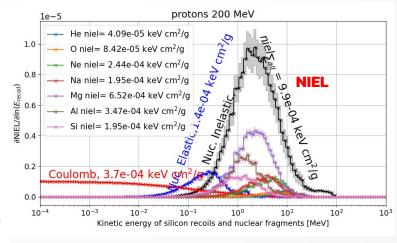


Integration of Geant4 PKA and TRIM NIEL



- The PKA Energy distribution can be sliced.
- The slice of an Energy E for ion with proton number Z can be correlated to particular NIEL (NIEL_{vacancy})
- B) A corresponding NIEL curve can be created

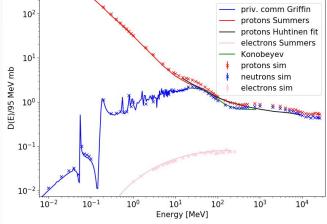




$$NIEL(T_0) = rac{N_A}{A} \sum_i \int_{T_{min}}^{T_{max}} iggl[Q(T)Tiggl(rac{d\sigma}{dT}iggr)_i dTiggr]$$

NIEL by high-energy particles

Producing NIEL curves



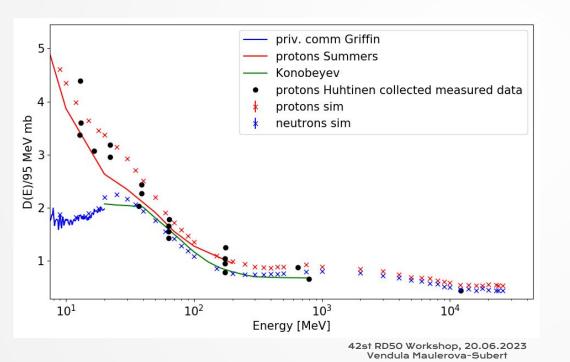
RD48 curve reproduced!

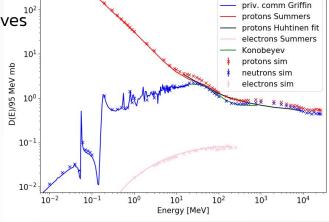
Producing NIEL curves

NIEL by high-energy particles

Benchmarking:

• Against the measurements: M. Huhtinen collected data (1993). Gives the theoretical understanding for the part of the curve only measured in RD-48 standard.





• RD48 curve reproduced!

Producing NIEL curves

NIEL by high-energy particles

Benchmarking:

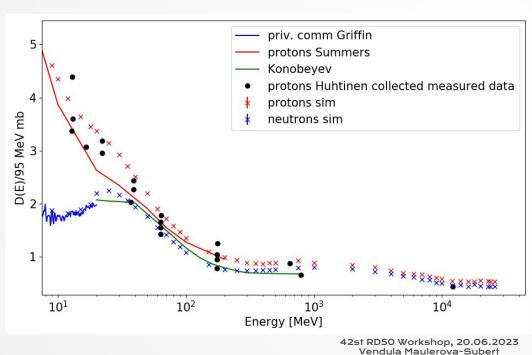
Against the measurements: M. Huhtinen collected data (1993). Gives

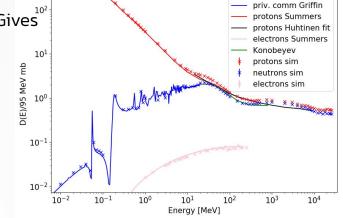
the theoretical understanding for the part of the curve only measured in RD-48 standard.

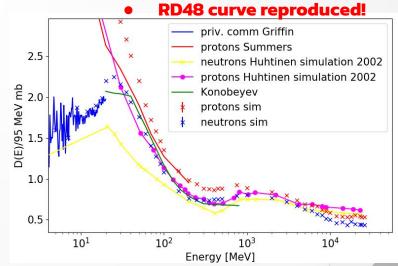
measured in RD-48 standard.

Against other simulations (Konobeyev, M. Huhtinen 2002)

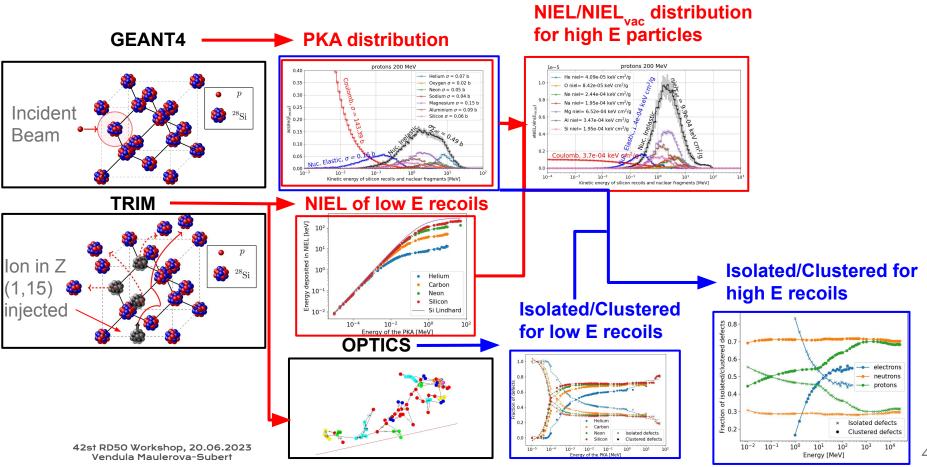
Gives confidence in the approach.



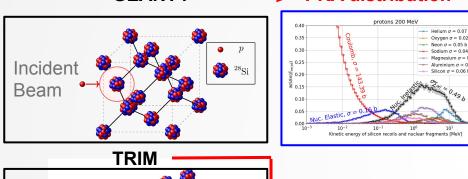


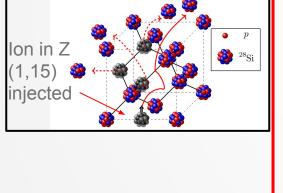


Overview of the simulations



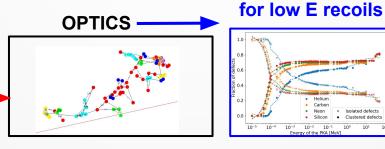
Atomic displacements by high-energy particles GEANT4 PKA distribution





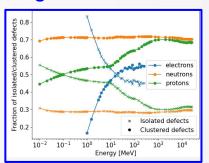
42st RD50 Workshop, 20.06.2023

Vendula Maulerova-Subert



Isolated/Clustered

Isolated/Clustered for high E recoils

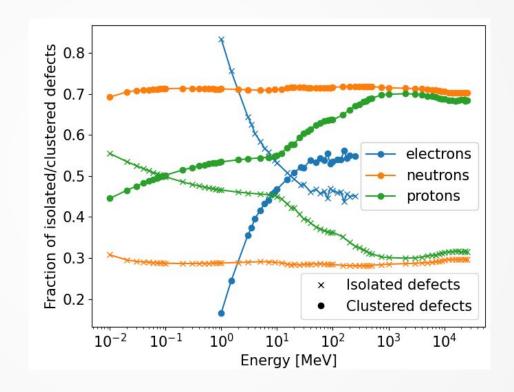


Isolated vs clustered vacancies

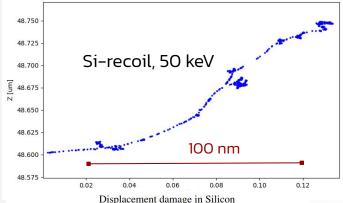
Results for minimum interatomic distance to be considered isolated vacancy.

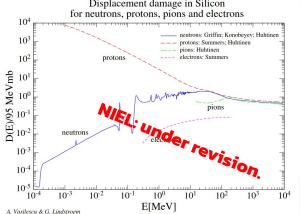
Here cluster is consider anything >= divacancy.

- For neutrons the ratio of the creation of isolated vacancies vs clustered is stable
- For protons the ratio of the isolated/clustered vacancies is decreasing as the Coulomb reaction becomes less of an effect compared to inelastic and elastic scattering.
- For electrons the ratio rapidly changes with energy before eventually reaching a plateau as well



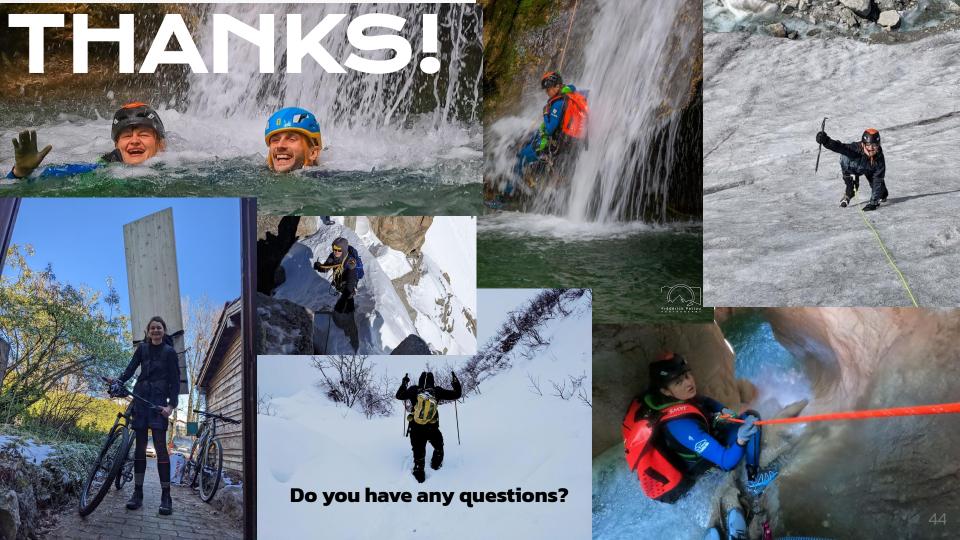
Outlook & next steps





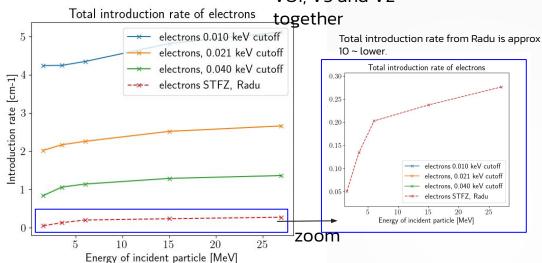
16) Data from A. Vasilescu (INPE Bucharest) and G. Lindström (Univ. of Hamburg), https://rd50.web.cern.ch/niel/

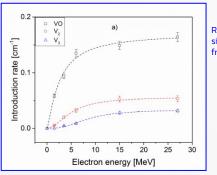
- Geant4 and FLUKA-based simulations have been carried out to produce Primary knocked-on atoms. Simulations agree within limit.
- TRIM simulations had been used to relate NIEL to the low-energy recoil
 ions.
- NIEL curves from literature (RD-48¹) were successfully reproduced.
- Several cluster-finding algorithms have been tested to establish differences between different particles and particle energies.
 - Promising datasets for protons, neutrons and electrons shown in this presentation.
- Ongoing work:
 - \circ Investigation of the relationship of NIEL (including phonons) and NIEL $_{\rm vacancv}$
 - Systematic studies on OPTICS with parameter tuning.
 - Studies and comparisons with the literature (cluster sizes, differences between vacancies and interstitials,..).
 - Measurements of introduction rates benchmarking of the clustered and isolated defects for protons and neutrons.
 - Extending studies to gammas.
 - Comparison to other simulations (TRIM, kinetic monte-carlo, molecular dynamics, quasi-chemical).



Electron induced damage



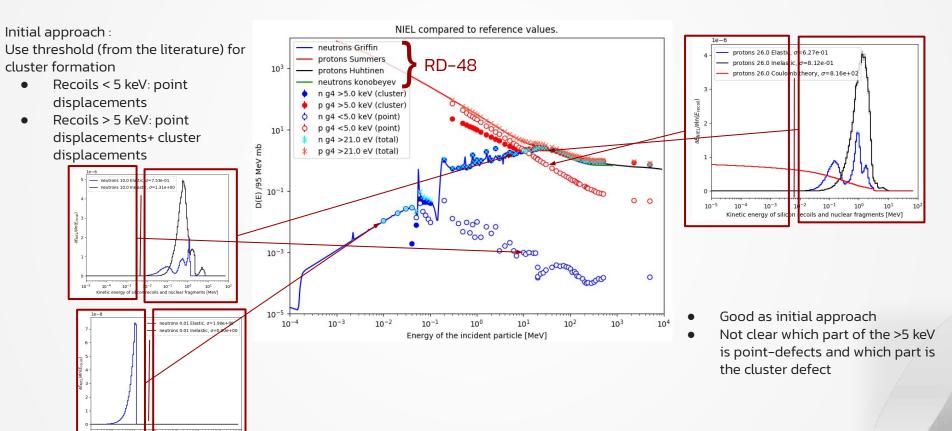




R. Radu: Bulk radiation damage in silicon: from point defects to clusters

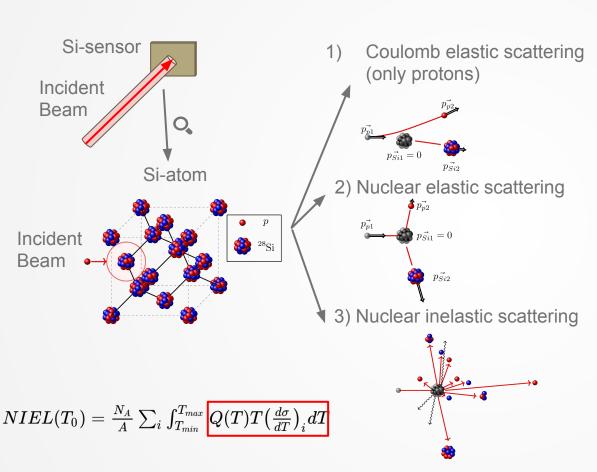
- The aim is to tune the parameters by using the measured values that we know.
- We would like to compare the total introduction rates and the rates between clustered and point defects.
- Tuning might depend on n, xi, cutoff limit.
- One of the options for the fine tuning would be to use a different constant for the processes that create only 1 PKA (a) and processes that create many SKA afterwards

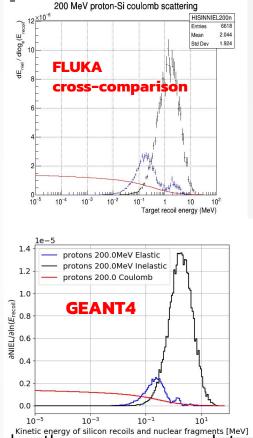
How to divide NIEL into clustered/isolated defects?



10-3

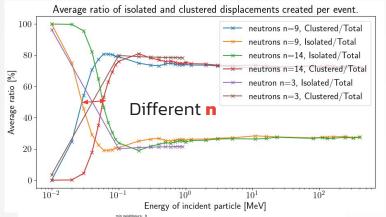
PKA cross section example

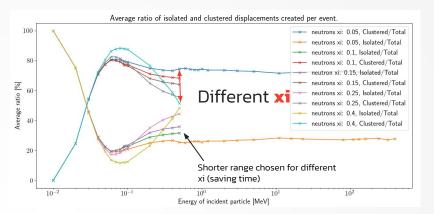


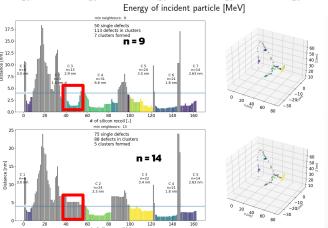


Area below the curve corresponds to the NIEL for respective reaction.

Paramater tuning: neutrons

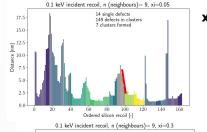


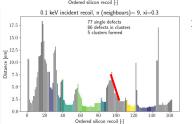


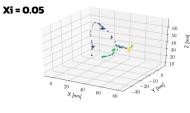


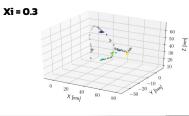
For the total ratio of Clustered vs isolated defects:

- n seems to shift the curve horizontally
- xi shifts the constant value the ratio eventually reaches.









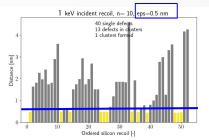
Deeper explanation of the parameters:

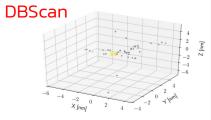
https://scikit-learn.org/stable/modules/generated/sklearn.cluster.OPTICS.html https://dl.acm.org/doi/pdf/10.1145/304181.304187

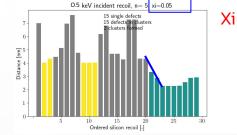
Tuning of the cluster model parameters

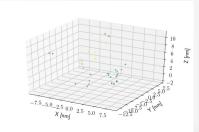
Method:

- Optics (number of samples, xi: steepness parameter)
- DBScan (number of samples, eps: extraction parameter)
 - The idea for DBScan could be to set eps=0.47 nm (2x interatomic distance) in order to be considered a cluster
 - The number of neighbours could be tuned by
 - <1-2 keV O clusters</p>
 - <12 keV 1 cluster</p>
 - >20 keV stable ratio of clusters and single displacements









Geant4 physics list, step functions

Derived from CERN Geant4 User's Workshop November 11th-15th 2002, John Apostolakis, Marc Verderi Ecole Polytechnique - LLR

For physics list:

8)

- AtRest functions: decay, e+ annihilation
- AlongStep functions: to describe continuous (inter)actions, occurring along the path of the particle, like ionisation
- PostStep actions: For describing point-like (inter)actions, like decay in flight, hard Radiation...

GetPhysicalInteractionLength():• Used to limit the step size:

- Used to limit the step size:
- either because the process « triggers » an interaction, a decay;
- Or any other reasons, like fraction of energy loss;
- geometry boundary;
- user's limit ..

G4VProcess: can implement any combination of AtRest, AlongStep, PostStep action

https://geant4.web.cern.ch/sites/default/files/geant4/collaboration/workshops/users2002/talks/lectures/PhysicsProcessesInGeneral.pdf

Geant4 physics list, step

Derived from CERN Geant4 User's Workshop November 11th-15th 2002, John Apostolakis, Marc Verderi Ecole Polytechnique - LLR

The stepping:

- The stepping treats processes generically:
- The stepping does not know what processes it is Handling
- The stepping imposes on the processes to Cooperate in their AlongStep actions; Compete for PostStep and AtRest actions;
- Processes can optionally emit also a «signal» to require particular treatment:
 - notForced: «standard» case;
 - forced: PostStepDoIt action is applied anyway;
 - conditionallyForced: PostStepDoIt
 - applied if AlongStep has limited the step;

The stepping: Stepping Invocation Sequence of Processes for a particle travelling

- At the beginning of the step, determine the step length: Consider all processes attached to the current G4Track; Define the step length as the smallest of the lengths among: All AlongStepGetPhysicalInteractionLenght()., All PostStepGetPhysicalInteractionLength()
- Apply all AlongStepDoIt() actions, « at once »:
 Changes computed from particle state at the
 beginning of the step; Accumulated in the G4Step;
 Then applied to the G4Track, from the G4Step.
- Apply PostStepDoIt() action(s) « sequentially », as long as the particle is alive: Apply PostStepDoIt() of process which proposed the smallest step length;
 apply « forced » and « conditionally forced » actions

Geant4 physics list, step

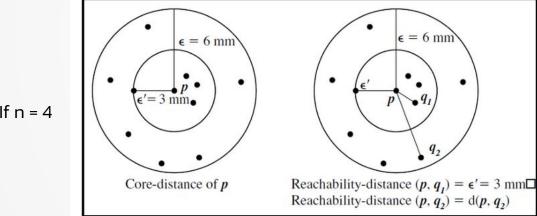
Derived from CERN Geant4 User's Workshop November 11th–15th 2002, John Apostolakis, Marc Verderi Ecole Polytechnique – LLR

- If the particle is at rest, is stable and can'tannihilate, it is killed by the tracking:To be more accurate: if a particle at rest has no« AtRest » actions defined, it is killed.
- Otherwise determine the lifetime: Take the smallest time among: All AtRestGetPhysicalInteractionLenght() Called «physical interaction length» but returns a time!
- 3. Apply the AtRestDoIt() action of the process which returned the smallest time.

OPTICS algorithm

OPTICS^{15,16} (Ordering points to identify the clustering structure) Important concepts:

- n (number of neighbours): user input
- Core distance: The minimum distance to make a point a core point, so that it contains number of neighbours n
- Reachability-distance:
 - If point < the core-distance reachability distance = core-distance
 - If point > core-distance, reachability distance = distance between the point and core point

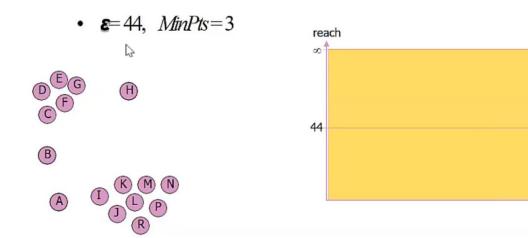


If n = 4

15) Ankerst, Mihael, Markus M. Breunig, Hans-Peter Kriegel, and Jörg Sander. "OPTICS: ordering points to identify the clustering structure." ACM SIGMOD Record 28, no. 2 (1999): 49-60. 16) Schubert, Erich, Michael Gertz. "Improving the Cluster Structure Extracted from OPTICS Plots." Proc. of the Conference "Lernen, Wissen, Daten, Analysen" (LWDA) (2018): 318-329.

Explanation from: https://www.youtube.com/watch?v=CVOmWaHOTA8&t=133s

Optics algorithm takes the points in a certain order and assigns them properties.



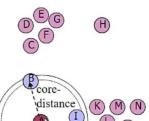
seedlist:

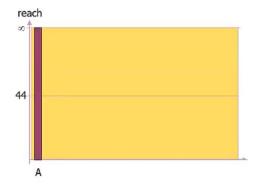
Min neighbours:2

Explanation from:

https://www.youtube.com/watch?v=CVOmWaHOTA8&t=133s

- Example Database (2-dimensional, 16 points)
- $\varepsilon=44$, MinPts=3





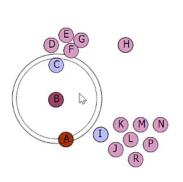
seedlist: (B,40) (I, 40)

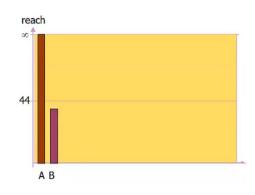
- A is the first point -> it's reachibility is infinite. (How far is the point from the last point?)
- B and C have are 40 units far away from A.

Explanation from:

https://www.youtube.com/watch?v=CVOmWaHOTA8&t=133s

- Example Database (2-dimensional, 16 points)
- $\epsilon=44$, MinPts=3





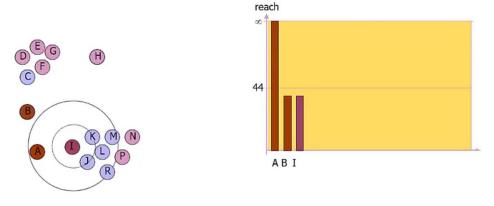
seedlist: (I, 40) (C, 40)

- Next point: B.
- Seedlist is updated and ordered by reachability.

Explanation from:

https://www.youtube.com/watch?v=CVOmWaHOTA8&t=133s

- Example Database (2-dimensional, 16 points)
- $\varepsilon=44$, MinPts=3



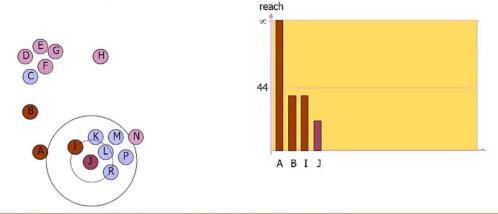
seedlist: (J, 20) (K, 20) (L, 31) (C, 40) (M, 40) (R, 43)

- Next point I.
- The core distance is much smaller (K and J are close).
- The seedlist is updated and ordered by reachability.

Explanation from:

https://www.youtube.com/watch?v=CVOmWaHOTA8&t=133s

- Example Database (2-dimensional, 16 points)
- **&=** 44, MinPts=3



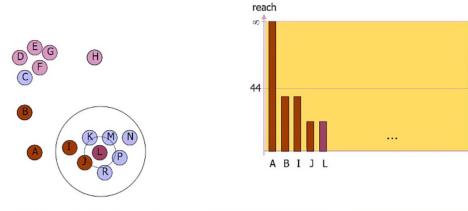
seedlist: (L, 19) (K, 20) (R, 21) (M, 30) (P, 31) (C, 40)

- Next point J
- The seedlist is updated and ordered by the rechability.

Explanation from:

https://www.youtube.com/watch?v=CVOmWaHOTA8&t=133s

- Example Database (2-dimensional, 16 points)
- $\varepsilon=44$, MinPts=3



seedlist: (M, 18) (K, 18) (R, 20) (P, 21) (N, 35) (C, 40)

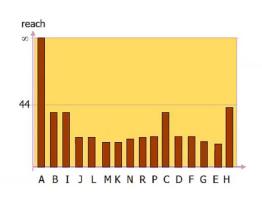
- Next point L
- The seedlist is updated and ordered by the rechability.

Explanation from:

https://www.youtube.com/watch?v=CVOmWaHOTA8&t=133s

• Example Database (2-dimensional, 16 points)





seedlist: -

The valleys represent the clusters.

Explanation from:

https://www.youtube.com/watch?v=CVOmWaHOTA8&t=133s

- Example Database (2-dimensional, 16 points)
- $\epsilon=44$, MinPts=3

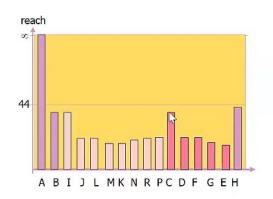








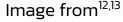


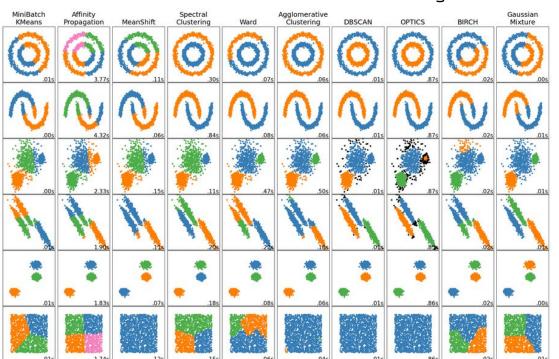


- The valleys represent the clusters.
- Parameter xi is parameter that is applied on the reachability plot in order to extract the clusters.

Clusters

- Cluster detection is a big topic in machine learning and mathematics
- Depending on its application, different algorithms are the best fit.

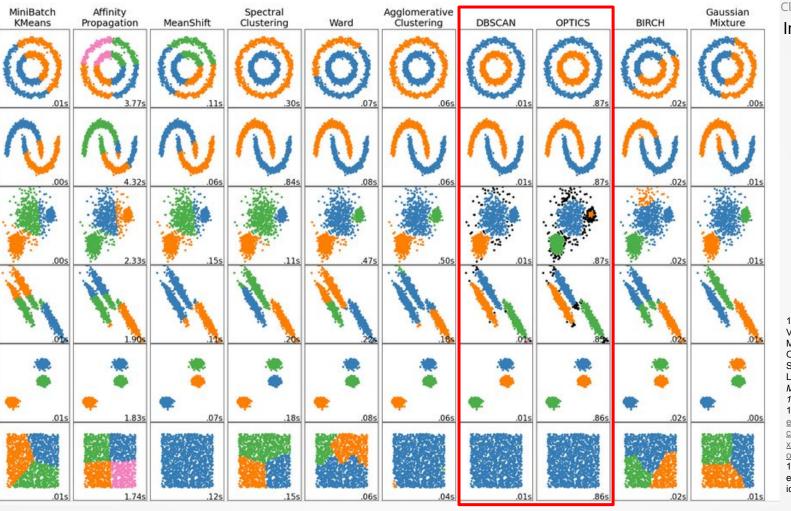




- Various clustering algorithms applied to 6 different sample datasets
- aim: identify clusters
- Algorithm must be able to process:
 - samples with large number of "outliers" (=single displacements for us)
 - samples with clusters of different shapes
 - samples with clusters with various densities

12) Pedregosa, F., Varoquaux, G., Gramfort, A., Michel, V., Thirion, B., Grisel, O., ... Duchesnay, E. (2011). Scikit-learn: Machine Learning in Python. *Journal of Machine Learning Research*. 12, 2825–2830.

13)https://scikit-learn.org/stable/auto_examples/cluster/plot_cluster_compariso n.html#sphx-glr-auto-examples-cluster-plot-cluster-comparison-py



Clustering algorithms

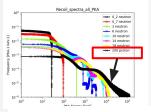
Image from 12,13

OPTICS
performs
better then
DBSCAN for
clusters with
varying
densities¹⁴.

12) Pedregosa, F., Varoquaux, G., Gramfort, A., Michel, V., Thirion, B., Grisel, O., ... Duchesnay, E. (2011). Scikit-learn: Machine Learning in Python. Journal of Machine Learning Research, 12, 2825–2830. 13)https://scikit-learn.org/stabl

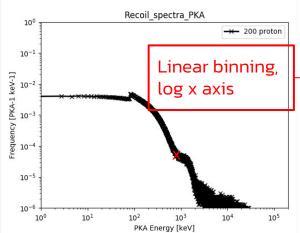
13)https://scikit-learn.org/stable/auto_examples/cluster/plot_cluster_comparison.html#sph_v-glr-auto-examples-cluster-plot-cluster-comparison-py

14)https://scikit-learn.org/stabl e/modules/clustering.html#opt ics



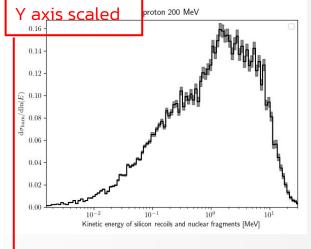
note: representing yaxis as $\partial \sigma_{barn}/\partial \ln(E)$

proton 200 MeV



0.000008
0.000007
Same graph:
Logarithmic
binning, log x
axis

0.000001
0.000001
0.000001
0.000001
Kinetic energy of silicon recoils and nuclear fragments [MeV]



1) PKA are summed and divided by the number of incident particles.

Conversion from σ to probability:

2) Logarithmic binning is used instead.

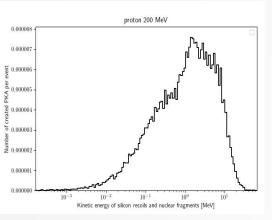
$$rac{I_{scattered}}{I_{incident}} = rac{N_A
ho_{Si} d}{m_{Si}} \sigma = 0.0005 \sigma_{barn}$$

3) Each content in a bin is divided by the length of the bin. That makes the y-axis linear. Furthermore the y axis is scaled by:

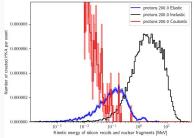
$$rac{10^{24}}{N_{targ}d}$$
 $d=0.01 {
m cm}$ $N_{targ}=rac{N_A
ho_{Si}}{m_{Si}}$

so that the **total area** corresponds to the **total cross section** of creating the PKA.

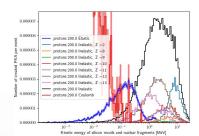
note: representing yaxis as $\partial E_{NIEL}/\partial \ln(E_{recoil})$



 PKA are summed and divided by the number of incident particles. Logarithmic binning is used instead, that makes the y axis linear. PKA are divided into Elastic and Inelastic parts (Coulomb part is added from QGSP_BIC_HP__SS simulation). Inelastic part is further divided into different spectra according to the Z number.



3) Inelastic part is further divided into different spectra according to the Z number.



4) For Coulomb, Elastic and Inelastic Si, Al and Mg recoils a Lindhard formulation is used¹².

For a recoil silicon in a silicon lattice, they read as:

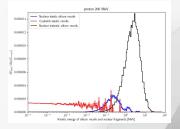
$$E_{de} = \frac{E_{Si}}{1 + k \times q(\epsilon)},$$
 (2)

with k = 0.1462, $\epsilon = 1.014 \times 10^{-2} \times Z_{\rm Si}^{-7/3} \times E_{\rm Si} = 2.147 \times 10^{-5} E_{\rm Si}$ and the universal function

$$g(\epsilon) = 3.4008 \times \epsilon^{1/6} + 0.40244 \times \epsilon^{3/4} + \epsilon$$
 (3)

- 5) For alphas¹³, Xapsos–Burke values were used to calculate NIEL.
- 6) Each content in a bin is divided by the length of the bin so that the **total area** corresponds to the **total NIEL**.

13) Xapsos, M.A. & Burke, E.A. & Badavi, F.F. & Townsend, Lawrence & Wilson, John & Jun, I.. (2005). NIEL calculations for high-energy heavy ions. Nuclear Science, IEEE Transactions on. 51. 3250 - 3254. 10.1109/TNS.2004.839136.



Bergmann, Benedikt, et al. "Ionizing Energy Depositions After Fast Neutron Interactions in Silicon." IEEE Transactions on Nuclear Science, vol. 63, Aug. 2016, pp. 2372–78. NASAADS, https://doi.org/10.1109/TNS.2016.2574961.